

GRF2004

Broadband Gain Block 0.1 to 10.0 GHz



Features

Reference: 5V/100mA/4.0 GHz

- Gain: 16.5 dB
- 0P1dB: 18.0 dBm
- OIP3: 31.0 dBm
- Eval Board NF: 1.9 dB
- Flexible Bias Voltage and Current
- Internally Matched to 50Ω
- Process: GaAs pHEMT

Applications

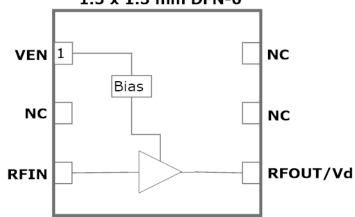
- Microwave Backhaul
- C/X-Band Amplifiers
- General Purpose Amplifiers
- Instrumentation

Product Description

GRF2004 is a broadband, low noise linear gain block designed for small cell, wireless infrastructure and other high performance RF applications. Due the extreme broadband nature of the device, data is presented for wideband RF measurements using network analyzer bias Tees. Under these conditions, the device exhibits good performance over 100 MHz to 10 GHz with minimal external components.

The device can be operated over a range of supply voltages from 1.8 to 5.0 V selectable Iddq for optimal efficiency and linearity.

Consult with the GRF applications engineering team for custom tuning/evaluation board data and device sparameters.



1.5 x 1.5 mm DFN-6

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Absolute Ratings:

Parameter	Symbol	Min.	Max.	Unit
Supply Voltage	Vdd	0	6.0	V
RF Input Power: (Load VSWR < 2:1; V _D : 5.0 volts)	P _{IN MAX}		15	dBm
RF Input Power: (Load VSWR < 2:1; V _{D:} <4.0 volts)	P _{IN MAX}		20	dBm
Operating Temperature (Package Heat Sink)	Т _{АМВ}	-40	105	°C
Maximum Channel Temperature (MTTF > 10^6 Hours)	Тмах		170	°C
Maximum Dissipated Power	PDISS MAX		600	mW
Electrostatic Discharge:				
Charged Device Model:	CDM	1500		V
Human Body Model:	HBM	250		V
Storage:				
Storage Temperature	T _{STG}	-65	150	°C
Moisture Sensitivity Level	MSL		1	



Caution! ESD Sensitive Device

Exceeding Absolute Maximum Rating conditions may cause permanent damage to the device.

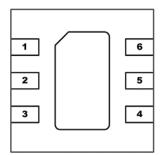
Note: For manufacturing information, see the Guerrilla-RF.com website for the following document located on the GRF2004 landing page: Manufacturing Note—MN-001 Product Tape and Reel, Solderability and Package Outline Specification.

Link to manufacturing note





Pin Out (Top View)



Pin Assignments:

Pin	Name	Description	Note		
1	VENABLE	Enable Voltage Input	VENABLE and series resistor set IDDQ. VENABLE < 0.2 volts disables device. On- die pull-down resistor will turn the part off if this node is allowed to float.		
2	NC	No Connect or Ground	No internal connection to die		
3	RF_In	LNA RF input	Internally matched 50 Ω . An external DC blocking cap must be used.		
4	RF_Out/VDD	LNA RF output	Internally matched 50 Ω . V_{DD} must be applied through a choke to this pin		
5	NC	No Connect or Ground	No internal connection to die		
6	NC	No Connect or Ground	No internal connection to die		
PKG BASE	GND	Ground	Provides DC and RF ground for LNA, as well as thermal heat sink. Recom- mend multiple 8 mil vias beneath the package for optimal RF and thermal performance. Refer to evaluation board top layer graphic on schematic page.		



Nominal Operating Parameters:

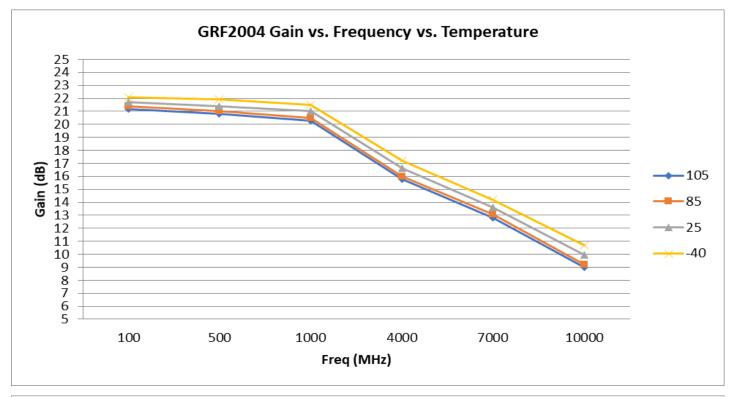
Parameter	Symbol	Specification		Unit	Condition	
Farameter		Min.	Тур.	Max.	Unit	Condition
Test Frequency	FTEST		4.0		GHz	V _{DD} = 5.0 V, T _A = 25 °C
Gain	S21	15.0	16.5		dB	
Evaluation Board Noise Figure	NF		1.9		dB	
Output 3rd Order Intercept	OIP3		31.0		dBm	0.0 dBm P _{OUT} per tone at 2 MHz Spacing (3999 and 4001 MHz)
Output 1dB Compression Point	OP1dB	16.0	18.0		dBm	
Switching Rise Time	T _{RISE}		800		ns	
Switching Fall Time	T _{FALL}		600		ns	
Supply Current	IDD		100		mA	
Enable Current	IENABLE		1.8		mA	
Leakage Current	ILEAKAGE		1		uA	Vdd: 5.0V; Venable: 0.0V
Thermal Data						
Thermal Resistance: (Infra-Red Scan)	Θјс		104		°C/W	On standard Evaluation Board
Channel Temperature @ +85 C Reference (Package heat sink)	TCHANNEL		137 (See note)		°C	VDD: 5.0 V; IDDQ: 100 mA; No RF; PDISS: 500 mW

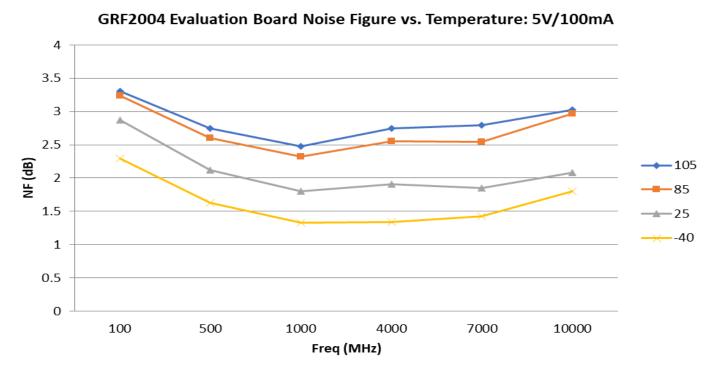
Note: MTTF >10^6 hours for TCHANNEL < =170 degrees C.

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GRF2004 Evaluation Board Measured Data: (0.1 to 10.0 GHz Bias T Measurements)

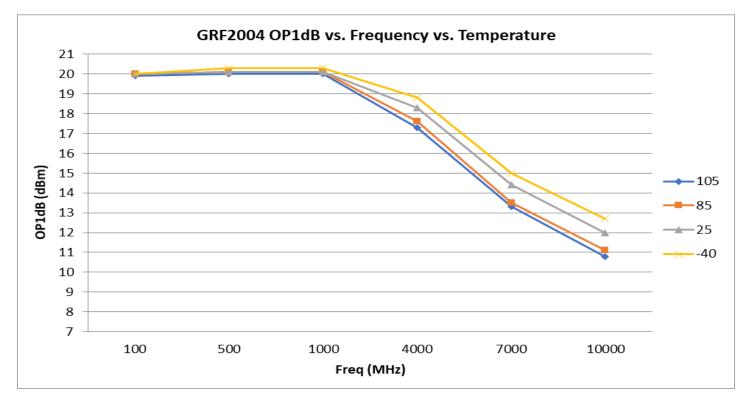


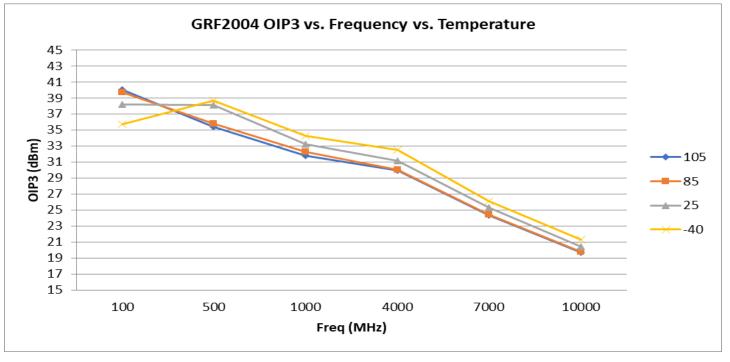


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GRF2004 Evaluation Board Measured Data: (0.1 to 10.0 GHz Bias T Measurements)





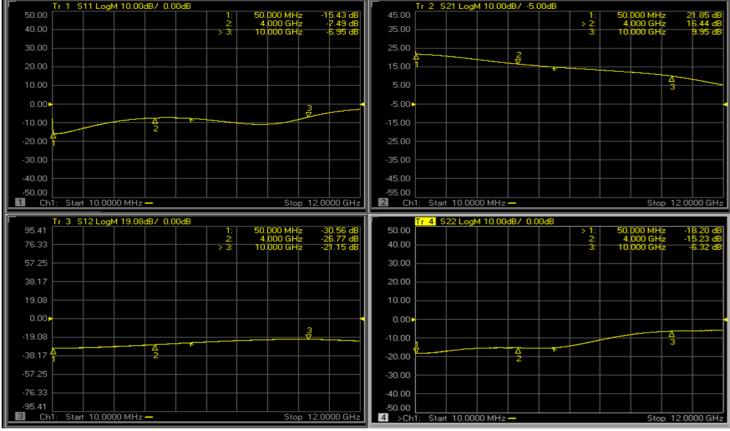
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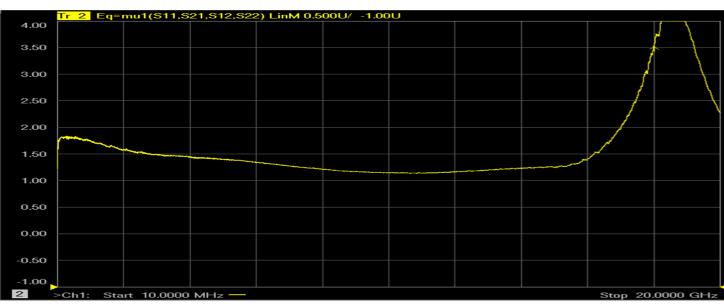


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GRF2004 Evaluation Board S-Pars and Stability Mu Factor: (0.1 to 10.0 GHz VNA Bias Ts)





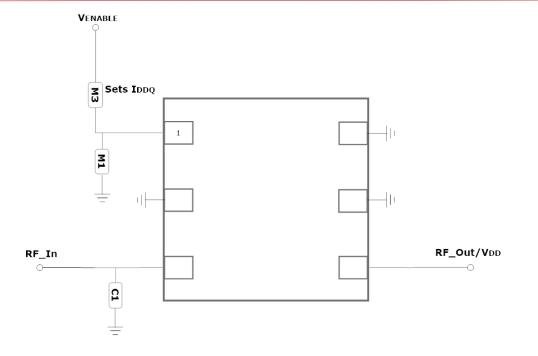
Note: Mu factor >= 1.0 implies unconditional stability.

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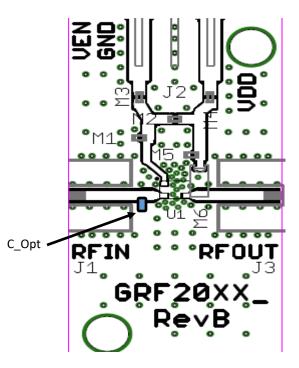


GRF2004 Broadband Gain Block

0.1 to 10.0 GHz



GRF2004 Application Schematic (0.1 to 10.0 GHz Eval Board)



GRF2004 Evaluation Board Assembly Drawing

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Manufacturer Substitution Component Туре Family Value Package Size Capacitor GRM 1000 pF 0402 M1 Murata ok M3 (See curves) Resistor Various 5% Sets Iddq 0402 ok C1 0.2 pF Capacitor Murata GJM 0402 ok GRF20XX_RevB Evaluation Board

GRF2004 Evaluation Board BOM for VNA S-parameter measurement

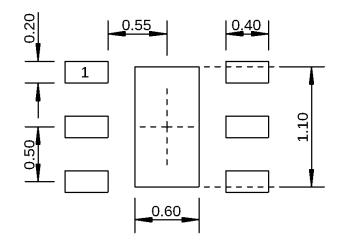
Note: C1 is added to test board input to enhance high frequency gain of the device.

Bias Resistor Selection Curves



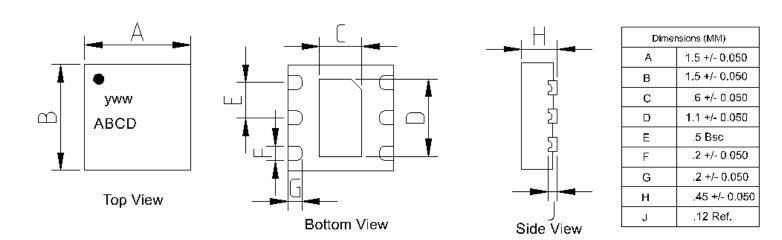
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Dimensions in millimeters





1.5 mm DFN-6 Package Dimensions

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Data Sheet Release Status:	Notes			
Advance	S-parameter and NF data based on EM simulations for the fully packaged device using foundry supplied transistor s-parameters. Linearity estimates based on de- vice size, bias condition and experience with related devices.			
Preliminary	All data based on evaluation board measurements in the Guerrilla RF Applications Lab.			
Released	All data based on device qualification data. Typically, this data is nearly identical to the data found in the preliminary version. Max and min values for key RF parameters are included.			

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